

A background image of a bright blue lightning bolt striking down from the top left towards the center of the slide.

*Enabling Advanced Power
Electronics Technologies for the
Next Generation Electric Utility Grid*

Workshop hosted by Sandia National Laboratories



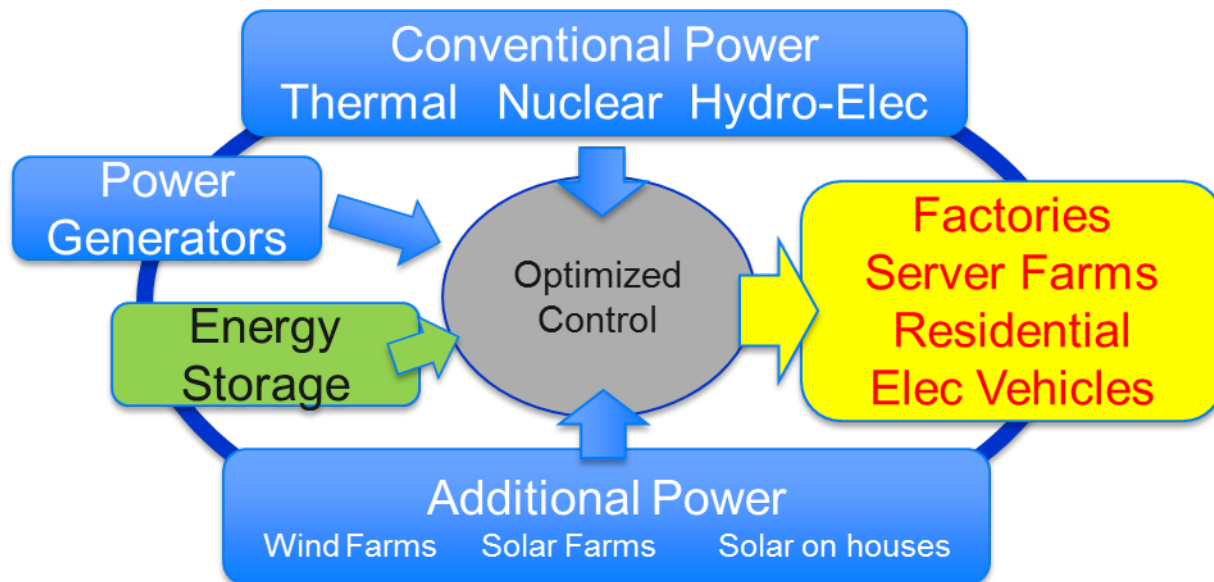
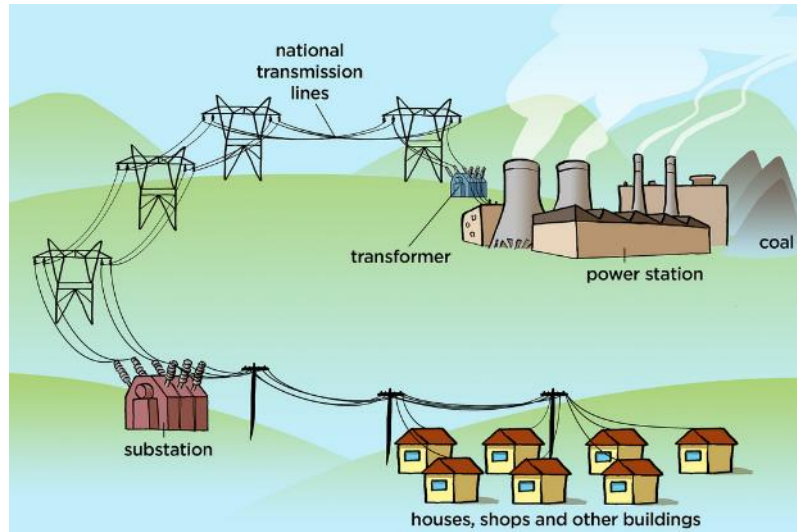
Session – 3

Components Needed: Capacitors

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Power Grid of Tomorrow



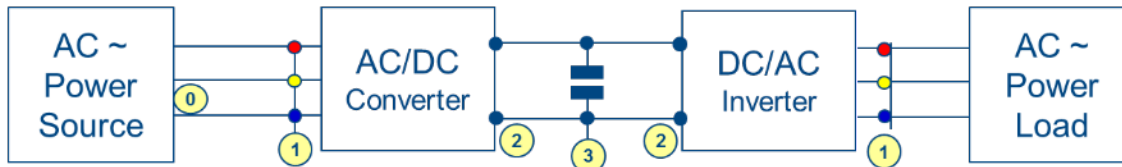
Future Power Grid

- Distributed generation, microgrids
- Smart automated distribution
- Distributed storage
- Smart, dynamic demand response
- Growing server farms and other end use
- Electric vehicles – charging everywhere

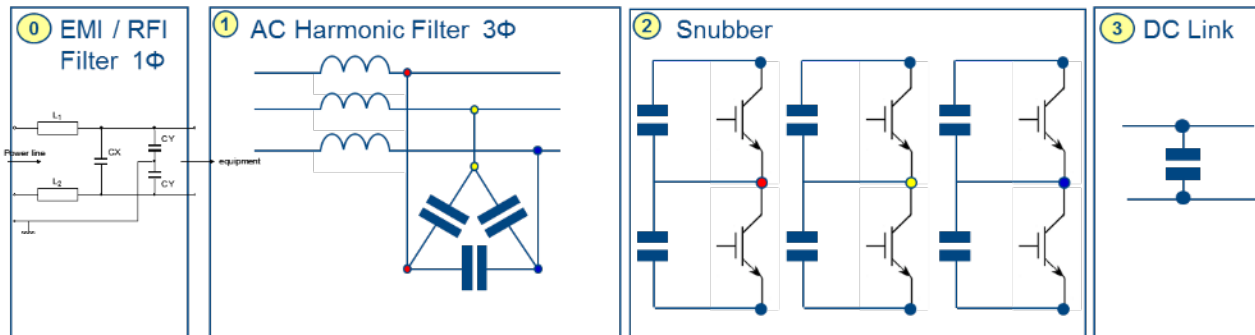
- ✓ **Seamless, Stable and Robust Integration**
- ✓ **EFFICIENCY!!! → WBG Solutions**

Capacitors in Power Electronics

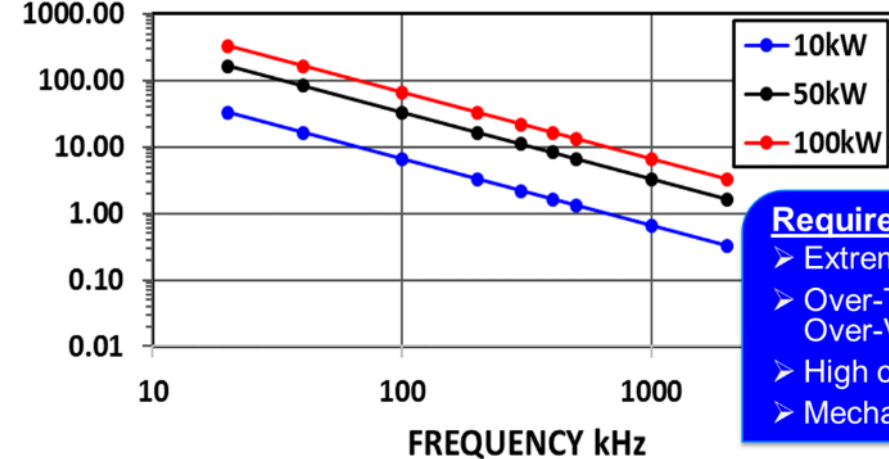
System Overview:



Typical Capacitor Types:



CAPACITANCE
μF



- Requirements**
- Extremely reliable
 - Over-Temperature and Over-Voltage Capable
 - High current capable
 - Mechanically Robust

* Source: Prof. R. Kennel, Technical University Munich, Germany

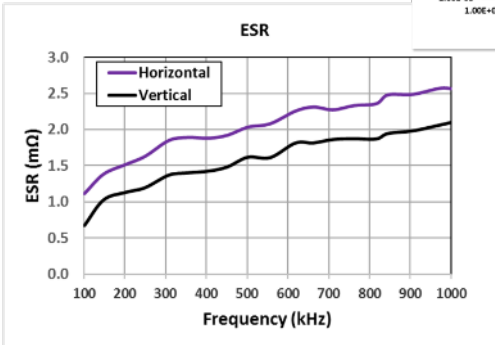
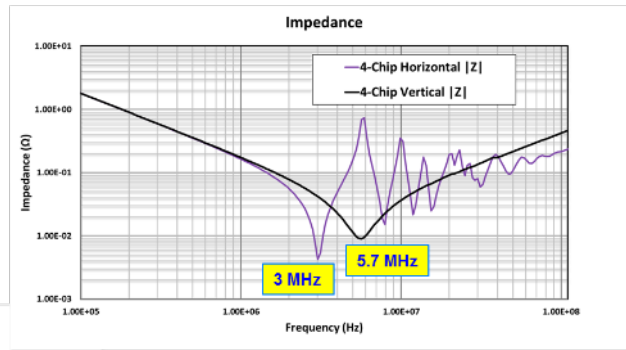
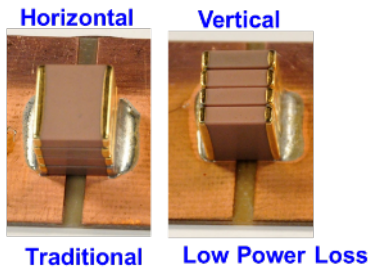
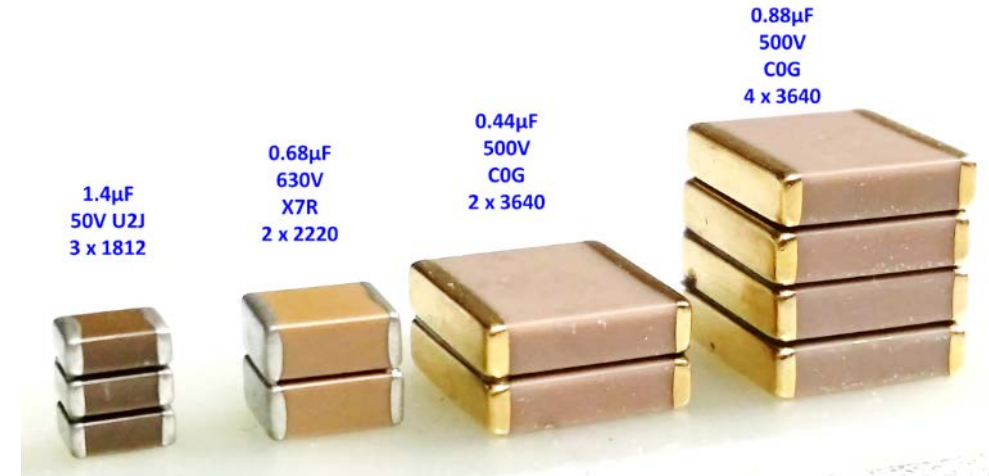
Trends in Capacitors for Power Electronics

- Need for improved power conversion efficiency is driving the development of new systems and components: WBG Semi's
- These trends are changing the requirements for capacitors used in Power Electronics:
 - Higher switching frequencies → Need low loss capacitor with high ripple current capability
 - High operating voltages → GaN (to 650V), SiC (to >1700V)
 - Higher temperatures → 125°C, 150°C, > 200°C for SiC

Capacitors for Future Power Applications

High Voltage Ni BME COG MLCC are an excellent choice in power applications because of their:

- Reliable performance at high temperatures (125-300°C)
- Stable capacitance with temperature and voltage
- High voltage ratings (no derating required!)
- **Very low dissipation factors (low loss) (<<0.1%)**
- **High IR (low leakage) & high breakdown voltages**
- **High ripple current capability**



Vertical Orientation has:

- Higher SRF
- Lower ESR

COG-0.88uF 3640 Stack

